

**Features**

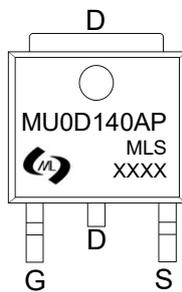
- High density cell design for ultra low  $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Green Device Available

**Product Summary**

$V_{DS}$	$R_{DS(ON)}$ MAX	$I_D$ MAX
-30V	3.7m $\Omega$ @-10V	-140A
	5.8m $\Omega$ @-4.5V	

**Application**

- Battery and loading switching
- Excellent package for good heat dissipation

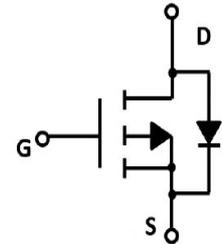


MU0D140AP: Device code  
 XXXX : Code

Marking and pin assignment



TO-252 top view



Schematic diagram



Pb-Free



RoHS



Halogen-Free

**Absolute Maximum Ratings (TA=25°C unless otherwise noted)**

Symbol	Parameter	Rating	Unit
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**Common Ratings (TC=25°C Unless Otherwise Noted)**

$V_{DS}$	Drain-Source Breakdown Voltage	-30	V	
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V	
$T_J, T_{STG}$	Storage Temperature Range	-55 to 175	$^{\circ}C$	
$I_S$	Diode Continuous Forward Current	$T_c=25^{\circ}C$	-140	A

**Mounted on Large Heat Sink**

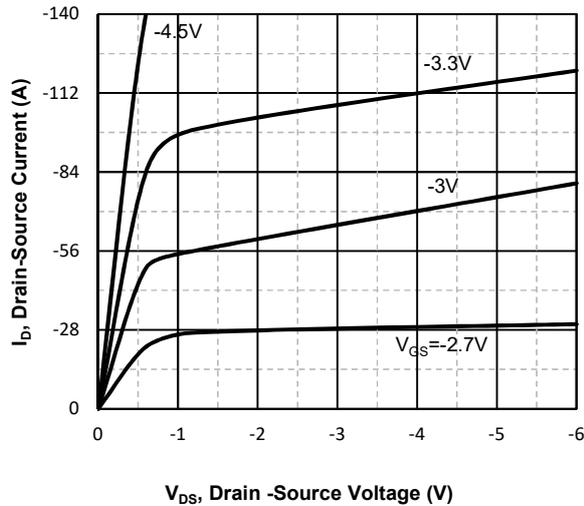
$I_{DM}$	Pulse Drain Current Tested	$T_c=25^{\circ}C$	-560	A
$I_D$	Continuous Drain Current	$T_c=25^{\circ}C$	-140	A
$P_D$	Maximum Power Dissipation	$T_c=25^{\circ}C$	132	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient		62.5	$^{\circ}C/W$

**Ordering Information (Example)**

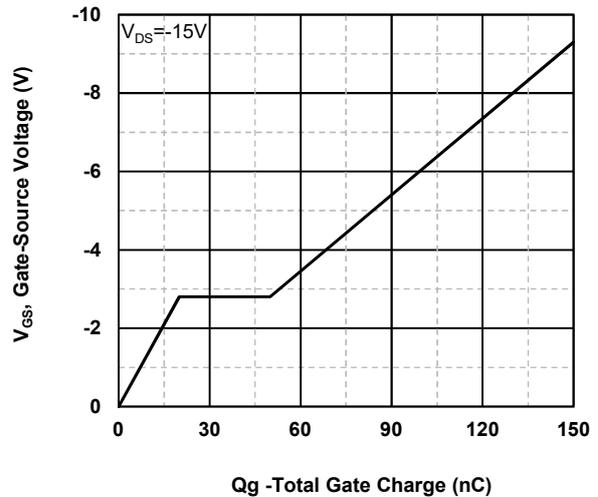
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MU0D140AP	TO-252	MU0D140AP	2,500	5,000	35,000	13"reel

Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-30	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	--	--	-1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.0	--	-2.5	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =-10V, I <sub>D</sub> =-30A	--	2.8	3.7	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-10A	--	4.6	5.8	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1MHz	--	7500	--	pF
C <sub>OSS</sub>	Output Capacitance		--	1200	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	940	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DD</sub> =-15V, I <sub>D</sub> =-30A, V <sub>GS</sub> =-10V	--	150	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	24	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	28	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =-15V, I <sub>D</sub> =-30A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω	--	25	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	35	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	100	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	50	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =-10A	--	--	-1.2	V

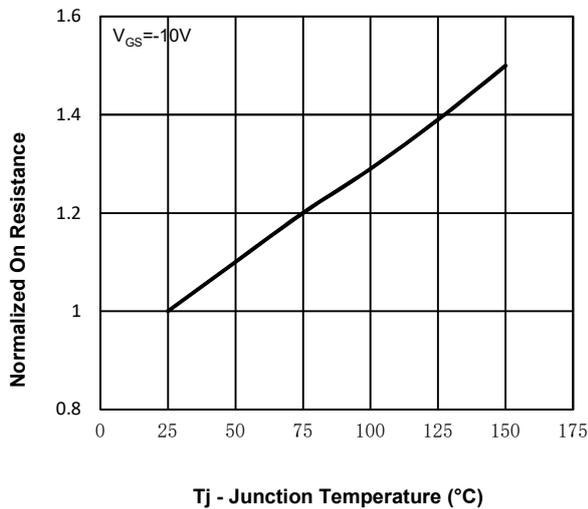
**Typical Operating Characteristics**



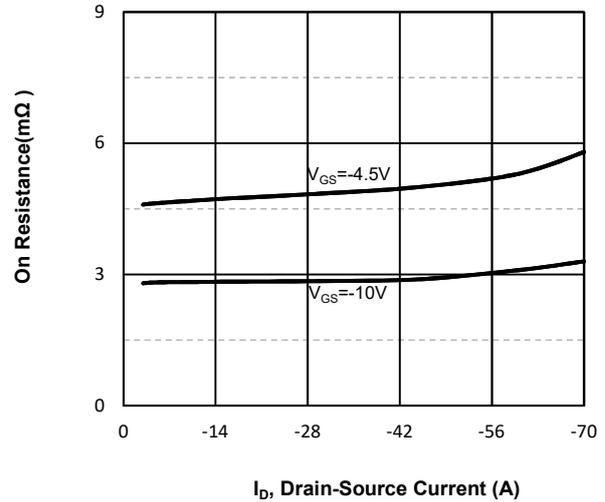
$V_{DS}$ , Drain -Source Voltage (V)  
Fig1. Typical Output Characteristics



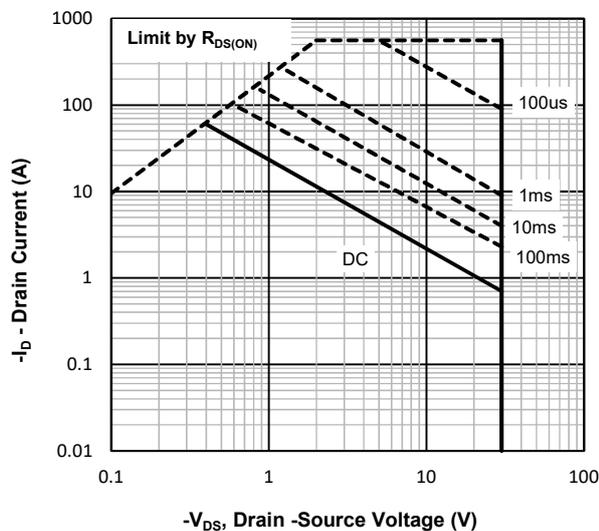
$Q_g$  -Total Gate Charge (nC)  
Fig2. Typical Gate Charge Vs. Gate-Source Voltage



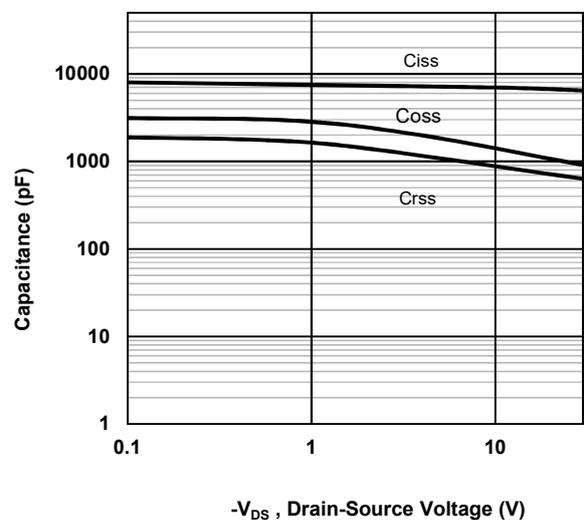
$T_j$  - Junction Temperature (°C)  
Fig3. Normalized On-Resistance Vs. Temperature



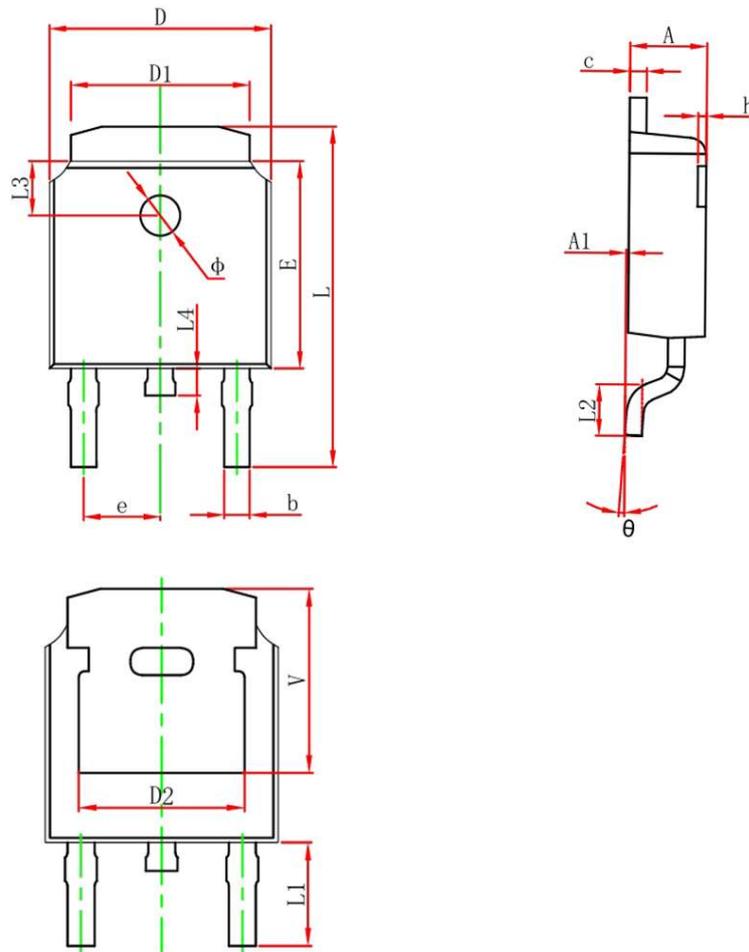
$I_D$ , Drain-Source Current (A)  
Fig4. On-Resistance Vs. Drain-Source Current



$V_{DS}$ , Drain -Source Voltage (V)  
Fig5. Maximum Safe Operating Area



$V_{DS}$ , Drain-Source Voltage (V)  
Fig6 Typical Capacitance Vs. Drain-Source Voltage

**TO-252 Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.450	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.386	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	